#### TITLE

by

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## List of Tables

# List of Symbols

Symbol	Description	Unit
A	vector potential	$\mathrm{V}\mathrm{s}\mathrm{m}^{-1}$
A	area	${ m cm}^2$
B	magnetic field	T
C	capacitance	F
E	electric field	$ m Vm^{-1}$
E	energy	eV (J)
$E_{ m F}$	Fermi energy	${ m eV}$
$E_g$	bandgap energy	$\mathrm{eV}$
$\hat{\mathbf{H}}$	Hamiltonian	eV (joule)
I	current	A
$I_{ m ds}$	drain current	A
L	length	μm
L	channel length	μm
m	mass	kg
$m^{\star}$	effective mass	kg
n	carrier density	${\rm cm}^{-2}$
n	charge carrier density	${ m Ccm^{-2}}$
$\hat{\mathbf{p}}$	momentum operator	$ m kgms^{-1}$
R	resistance	$k\Omega  \mu m  (\Omega)$
$R_c$	contact resistance	$\mathrm{k}\Omega\mathrm{\mu m}$
$R_H$	Hall coefficient	$\mathrm{m^3C^{-1}}$
$\hat{\mathbf{s}}$	spin operator	$\hbar \; (\mathrm{J} \mathrm{s})$
T	temperature	K
T	temperature	K

V	voltage	V
$V_{ m bg}$	backgate voltage	V
$V_{ m ds}$	drain voltage	V
$V_{ m H}$	Hall voltage	V
w	channel width	μm
$\mu$	magnetic moment	${ m eVT^{-1}}$
$\mu$	mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
$\mu_e$	electron mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
$\mu_{ ext{FE}}$	field-effect mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
$\mu_{ m H}$	Hall mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
$\mu_p$	hole mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
ho	resistivity	$\Omega\mathrm{cm}$
$ ho_{xx}$	longitudinal resistivity	$\Omega$
$ ho_{xy}$	transverse resistivity	Ω
$\sigma$	conductivity	μS
$\sigma_{xx}$	longitudinal conductivity	μS
$\sigma_{xy}$	transverse conductivity	μS
au	lifetime	S
$\Phi_{ m B}$	barrier height	eV
$\Phi_{\mathrm{B}n}$	electron barrier height	$\mathrm{eV}$
$\Phi_{\mathrm{B}p}$	hole barrier height	$\mathrm{eV}$
$\Phi_M$	metal work function	$\mathrm{eV}$
$\Phi_S$	semiconductor work function	$\mathrm{eV}$
χ	electron affinity	$\mathrm{eV}$
$\chi_S$	semiconductor electron affinity	$\mathrm{eV}$
$\omega_c$	cyclotron frequency	$_{ m Hz}$

## List of Physical Constants

Symbol	Quantity	Value
$k_{ m B}$	Boltzmann's constant	$1.38066 \times 10^{-23}\mathrm{JK^{-1}}$
		$8.61734 \times 10^{-5}\mathrm{eV}\mathrm{K}^{-1}$
$\epsilon_0$	dielectric constant	$8.85418 \times 10^{-12} \mathrm{A}^2 \mathrm{s}^4 \mathrm{kg}^{-1} \mathrm{m}^{-3}$
e	elementary charge	$1.60218 \times 10^{-19} \mathrm{C}$
$\mathrm{eV}$	electron volt	$1.60218 \times 10^{-19}\mathrm{J}$
c	speed of light	$2.99792\times10^8\mathrm{ms^{-1}}$
h	Planck's constant	$6.62607 \times 10^{-34}\mathrm{Js}$
$\hbar$	reduced Planck's constant	$1.05457 \times 10^{-34}\mathrm{Js}\;(h/2\pi)$
$R_{\mathrm{K-90}}$	von Klitzing constant	$25812.80745555\Omega$
$m_e$	electron mass	$9.109383 \times 10^{-31} \mathrm{kg}$
$k_{ m B}T$	Thermal energy	$0.02586\mathrm{eV}\ (T=27^{\circ}\mathrm{C})$
		$0.02526\mathrm{eV}\ (T=20^{\circ}\mathrm{C})$
$\mu_B$	Bohr magneton	$9.274009\times 10^{-24}\mathrm{JT^{-1}}$
		$5.788381 \times 10^{-5}\mathrm{eV}\mathrm{T}^{-1}$
		$e\hbar/2m_e$ (atomic units)

Source: CODATA Recommende Values of the Fundamental Physics Constants: 2014, Mohr  $et\ al.^1$ 

## Acronyms

SB Schottky barrier

## References

[1] P. J. Mohr, D. B. Newell, and B. N. Taylor. Codata recommended values of the fundamental physical constants: 2014. *ArXiv e-prints*, jul 2015.